

# FGP15N60UNDF 600 V, 15 A Short Circuit Rated IGBT

## Features

- Short Circuit Rated 10us
- High Current Capability
- High Input Impedance
- Fast Switching
- RoHS Compliant

## **Applications**

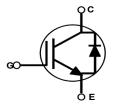
• Sewing Machine, CNC, Home Appliances, Motor Control

### March 2013

# **General Description**

Using advanced NPT IGBT technology, Fairchild<sup>®</sup>'s the NPT IGBTs offer the optimum performance for low-power inverterdriven applications where low-losses and short-circuit ruggedness features are essential, such as sewing machine, CNC, motor control and home appliances.





# **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		600	V
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	30	A
	Collector Current	@ T <sub>C</sub> = 100°C	15	A
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	45	A
I <sub>F</sub>	Diode Forward Current	@ T <sub>C</sub> = 25°C	15	A
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	178	W
' D	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	71	W
TJ	Operating Junction Temperature		-55 to +150	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	Oo

Notes:

1: Repetitive test , Pulse width=100 usec , Duty=0.2,  $V_{GE}$ =13.5 V

## **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case		0.7	°C/W
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case		2.3	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)		62.5	°C/W

		Ackage Packaging Type TO220 Tube		Qty per Tube		Max Qty per Box			
							-		
		· · · · ·			l.	-1		I.	
Electric	al Cha	racteristics of t	he I	<b>GBT</b> T <sub>C</sub> = 2	5°C unless otherwise noted				
Symbol	Parameter			Test Conditions		Min.	Тур.	Max.	Unit
Off Charac	teristics								
BV <sub>CES</sub>	Collector	to Emitter Breakdown Vo	oltage	V <sub>GE</sub> = 0 V, I	<sub>C</sub> = 250 μA	600	-	-	V
I <sub>CES</sub>		Cut-Off Current	0	$V_{CE} = V_{CES}, V_{GE} = 0 V$		-	-	1	mA
I <sub>GES</sub>	G-E Leak	age Current		V <sub>GE</sub> = V <sub>GES</sub>	-	-	-	±10	μA
On Charge	toriotico				-			I	I
On Charac V <sub>GE(th)</sub>		shold Voltage		I <sub>C</sub> = 15 mA, V <sub>CE</sub> = V <sub>GE</sub>		5.5	6.8	8.5	V
				$I_{\rm C} = 15 \text{ A}, V_{\rm C}$		-	2.2	2.7	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage			$I_{C} = 15 \text{ A}, V_{GE} = 15 \text{ V}$ $I_{C} = 15 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$		-	2.7	-	V
Dumomio O		41		I					
Dynamic C C <sub>ies</sub>	Input Cap					_	619	_	pF
C <sub>oes</sub>		utput Capacitance		$V_{CE} = 30 V_{V_{CE}} = 0 V_{OE}$		-	80	_	pF
C <sub>res</sub>	· ·	Transfer Capacitance		_ f = 1 MHz		_	24	_	pF
les									P.
Switching								1	
t <sub>d(on)</sub>	Turn-On I	Delay Time				-	9.3	-	ns
t <sub>r</sub>	Rise Time	e		$V_{CC} = 400 \text{ V}, \text{ I}_{C} = 15 \text{ A},$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ Inductive Load, $T_{C} = 25^{\circ}\text{C}$		-	9.8	-	ns
t <sub>d(off)</sub>	Turn-Off	Delay Time				-	54.8	-	ns
t <sub>f</sub>	Fall Time					-	9.9	12.8	ns
E <sub>on</sub>	Turn-On	Switching Loss				-	0.37	-	mJ
E <sub>off</sub>	Turn-Off	Switching Loss				-	0.067	-	mJ
E <sub>ts</sub>	Total Swi	tching Loss				-	0.44	-	mJ
t <sub>d(on)</sub>	Turn-On I	Delay Time				-	8.9	-	ns
t <sub>r</sub>	Rise Time	e		− − − − − − − − − − − − − − − − − − −	-	9.9	-	ns	
t <sub>d(off)</sub>	Turn-Off	Delay Time			-	56.6	-	ns	
t <sub>f</sub>	Fall Time			R <sub>G</sub> = 10 Ω, V <sub>GE</sub> = 15 V,		-	13.2	-	ns
E <sub>on</sub>	Turn-On	Switching Loss		Inductive Load, T <sub>C</sub> = 125 <sup>o</sup> C	-	0.54	-	mJ	
E <sub>off</sub>	Turn-Off	Switching Loss		-		-	0.11	-	mJ
E <sub>ts</sub>	Total Swi	tching Loss				-	0.65	-	mJ
T <sub>sc</sub>	Short Circuit Withstand Time		V <sub>CC</sub> = 350 V R <sub>G</sub> = 100 Ω, T <sub>C</sub> = 150°C	/, , V <sub>GE</sub> = 15 V,	10	-	-	μs	

FGP15N60UNDF 600 V, 15 A Short Circuit Rated

# Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

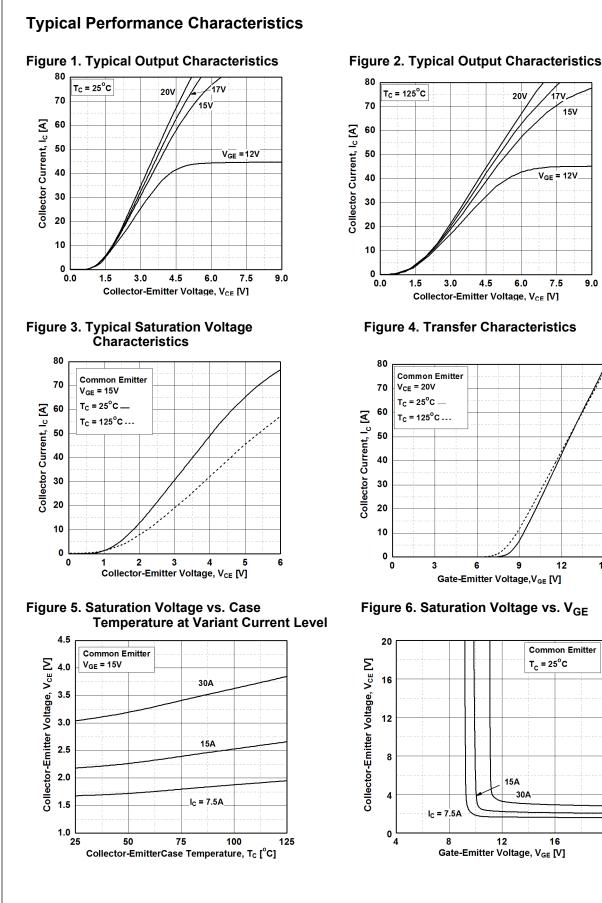
Qg	Total Gate Charge		-	43	-	nC
Q <sub>ge</sub>	Gate to Emitter Charge	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 15 A, V <sub>GE</sub> = 15 V	-	6	-	nC
Q <sub>gc</sub>	Gate to Collector Charge		-	26	-	nC

# Electrical Characteristics of the Diode $T_C = 25^{\circ}C$ unless otherwise noted

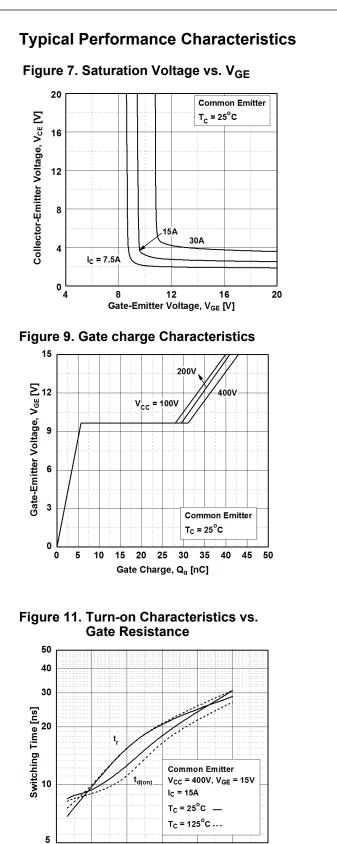
Symbol	Parameter	Test Conditions		Min.	Тур.	Мах	Unit
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 15 A	T <sub>C</sub> = 25°C	-	1.6	2.2	v
* FIM	Diodo i olivara Voltago		T <sub>C</sub> = 125°C	-	1.5	-	
t	rr Diode Reverse Recovery Time	I <sub>F</sub> =15 A, dI <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25 <sup>o</sup> C	-	82.4		ns
l <sup>v</sup> rr			T <sub>C</sub> = 125°C	-	142	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge		T <sub>C</sub> = 25 <sup>o</sup> C	-	213	-	nC
			T <sub>C</sub> = 125°C	-	541	-	

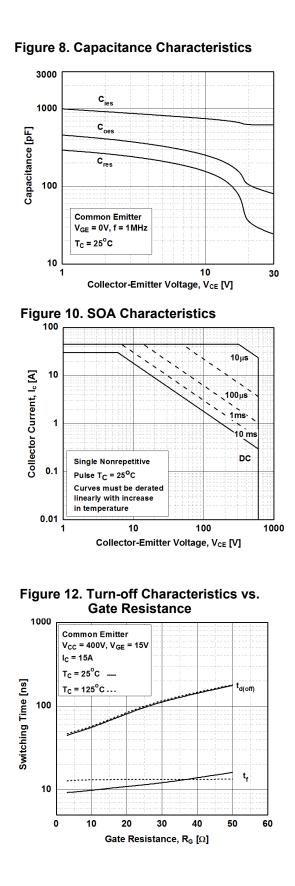
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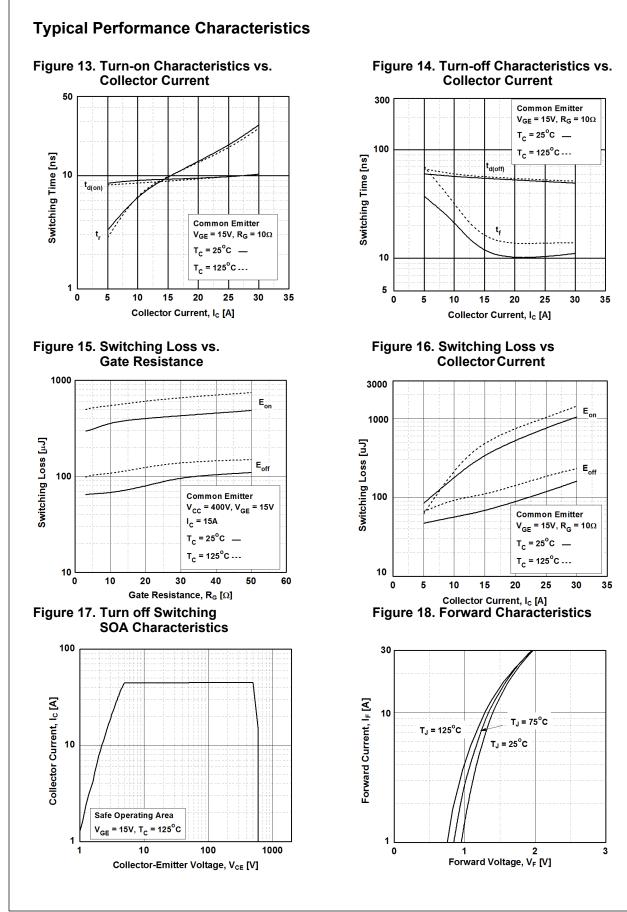
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Gate Resistance,  $R_{G}$  [ $\Omega$ ]

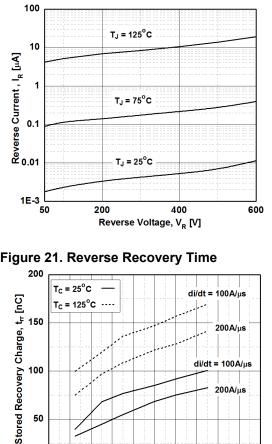


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# **Typical Performance Characteristics**

## Figure 19. Reverse Recovery Current





Forward Current, I<sub>F</sub> [A]

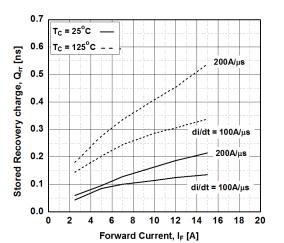
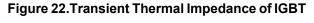
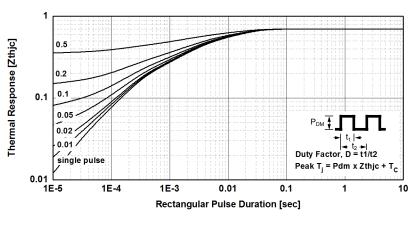
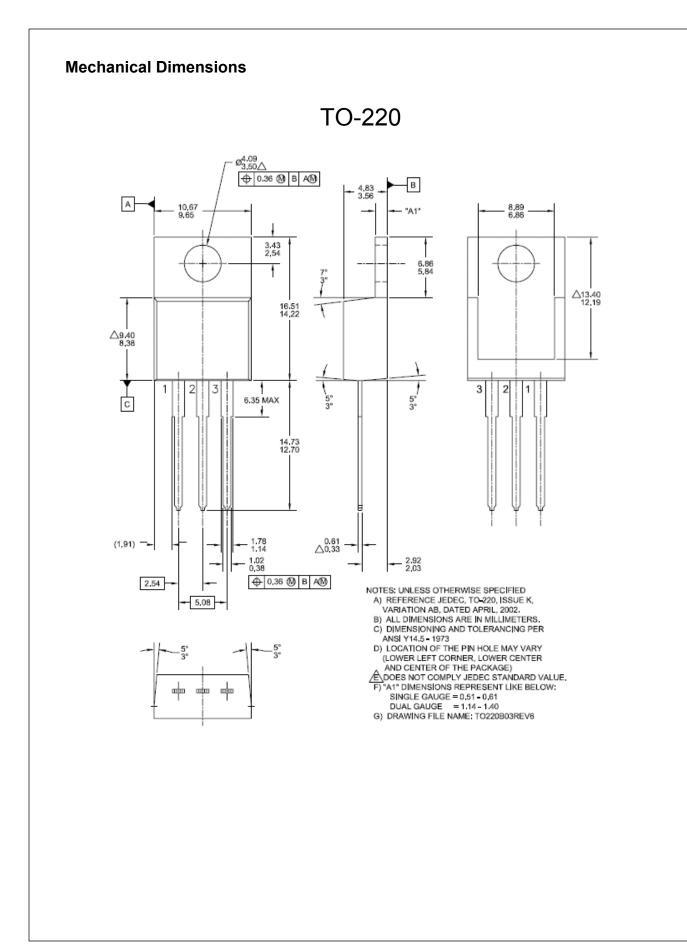


Figure 21. Reverse Recovery Time









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Obsolete	Not In Production	Semiconductor. The datasheet is for reference information only.		